Electronic Supplementary Information (ESI)

Realization of highly photoresponsive azobenzene-functionalized monolayers

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Fig. S1 Changes in the normalized absorbance at λ_{max} of $\pi - \pi^*$ band of (a) MeSH and (b) EtSH in dichloromethane as a function of dark incubation after UV light irradiation. The ratio of the trans form of EtSH was obtained from ¹H NMR data (in CD₂Cl₂).



Fig. S2 Changes in (A_t-A_{ap}) of cis-EtSH SAMs as a function of thermal cis-to-trans isomerization time after UV light irradiation. A_{ap} and A_t correspond to absorbance at λ_{max} of as-prepared SAMs and after dark incubation for time (t), respectively.